



200 mA Output Current High-Speed Amplifier

AD8010

FEATURES

200 mA of Output Current

9 Ω Load

SFDR -54 dBc @ 1 MHz

Differential Gain Error 0.04%, $f = 4.43$ MHz

Differential Phase Error 0.06°, $f = 4.43$ MHz

Maintains Video Specifications Driving Eight Parallel

75 Ω Loads

0.02% Differential Gain

0.03° Differential Phase

0.1 dB Gain Flatness to 60 MHz

THD -72 dBc @ 1 MHz, $R_L = 18.75 \Omega$

IP3 42 dBm @ 5 MHz, $R_L = 18.75 \Omega$

1 dB Gain Compression 21 dBm @ 5 MHz, $R_L = 100 \Omega$

230 MHz -3 dB Bandwidth, $G = +1$, $R_L = 18.75 \Omega$

800 V/ μ s Slew Rate, $R_L = 18.75 \Omega$

25 ns Settling Time to 0.1%

Available in 8-Lead DIP, 16-Lead Wide Body SOIC and
Thermally Enhanced 8-Lead SOIC

APPLICATIONS

Video Distribution Amplifier

VDSL, xDSL Line Driver

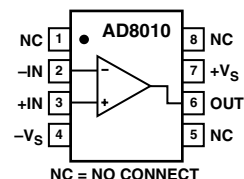
Communications

ATE

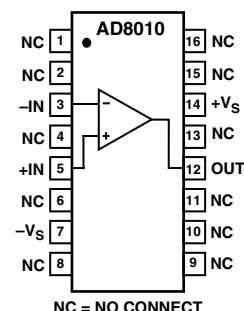
Instrumentation

CONNECTION DIAGRAMS

8-Lead DIP and SOIC



16-Lead Wide Body SOIC



PRODUCT DESCRIPTION

The AD8010 is a low power, high current amplifier capable of delivering a minimum load drive of 175 mA. Signal performance such as 0.02% and 0.03° differential gain and phase error is maintained while driving eight 75 Ω back terminated video lines. The current feedback amplifier features gain flatness to 60 MHz and -3 dB ($G = +1$) signal bandwidth of 230 MHz and only requires a typical of 15.5 mA supply current from ± 5 V supplies. These features make the AD8010 an ideal component for Video Distribution Amplifiers or as the drive amplifier within high data rate Digital Subscriber Line (VDSL and xDSL) systems.

The AD8010 is an ideal component choice for any application that needs a driver that will maintain signal quality when driving low impedance loads.

The AD8010 is offered in three package options: an 8-lead DIP, 16-lead wide body SOIC and a low thermal resistance 8-lead SOIC, and operates over the industrial temperature range of -40°C to +85°C.

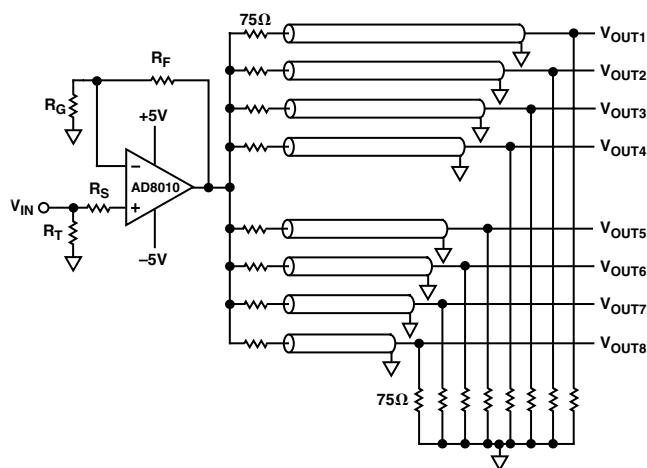


Figure 1. Video Distribution Amplifier

REV. B

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AD8010* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- Universal Evaluation Board for Single High Speed Operational Amplifiers

DOCUMENTATION

Application Notes

- AN-356: User's Guide to Applying and Measuring Operational Amplifier Specifications
- AN-649: Using the Analog Devices Active Filter Design Tool
- AN-692: Universal Precision Op Amp Evaluation Board

Data Sheet

- AD8010: 200 mA Output Current High Speed Amplifier Data Sheet

User Guides

- UG-755: 8-Lead SOIC Amplifier Evaluation Board User Guide

TOOLS AND SIMULATIONS

- AD8010 SPICE Macro-Model

REFERENCE MATERIALS

Product Selection Guide

- Amplifiers for Video Distribution

Tutorials

- MT-034: Current Feedback (CFB) Op Amps
- MT-051: Current Feedback Op Amp Noise Considerations
- MT-057: High Speed Current Feedback Op Amps
- MT-059: Compensating for the Effects of Input Capacitance on VFB and CFB Op Amps Used in Current-to-Voltage Converters

DESIGN RESOURCES

- AD8010 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all AD8010 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

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AD8010—SPECIFICATIONS

(@ 25°C, $V_S = \pm 5\text{ V}$, $G = +2$, $R_L = 18.75\ \Omega$, $R_{S+} = 150\ \Omega$, $R_F = R_G = 604\ \Omega$ (R-16), $R_F = R_G = 562\ \Omega$ (N-8), $R_F = R_G = 499\ \Omega$ (R-8). $T_{MIN} = -40^\circ\text{C}$, $T_{MAX} = +85^\circ\text{C}$ unless otherwise noted)

Model	Conditions	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE					
–3 dB Bandwidth	$G = +1$, $V_{OUT} = 0.2\text{ V p-p}$	180	230		MHz
	$G = +2$, $V_{OUT} = 0.2\text{ V p-p}$	130	190		MHz
0.1 dB Bandwidth	$V_{OUT} = 0.2\text{ V p-p}$	30	60		MHz
Large Signal Bandwidth	$V_{OUT} = 4\text{ V p-p}$		90		MHz
Peaking	$V_{OUT} = 0.2\text{ V p-p}$, $< 5\text{ MHz}$		0.02		dB
Slew	$V_{OUT} = 2\text{ V p-p}$		800		V/ μs
Rise and Fall Time	$V_{OUT} = 2\text{ V p-p}$		2.0		ns
Settling Time	0.1%, $V_{OUT} = 2\text{ V p-p}$		25		ns
NOISE/HARMONIC PERFORMANCE					
Distortion	$V_{OUT} = 2\text{ V p-p}$				
2nd Harmonic	1 MHz		–73		dBc
	5 MHz		–58		dBc
	10 MHz		–53		dBc
	10 MHz, $R_L = 39\ \Omega$		–67		dBc
	20 MHz		–44		dBc
3rd Harmonic	1 MHz		–77		dBc
	5 MHz		–63		dBc
	10 MHz		–57		dBc
	10 MHz, $R_L = 39\ \Omega$		–63		dBc
	20 MHz		–50		dBc
IMD	5 MHz $\Delta f = 10\text{ kHz}$		–73		dBc
IP3	5 MHz		42		dBm
1 dB Gain Compression	5 MHz		21		dBm
Input Noise Voltage	$f = 10\text{ kHz}$		2		$\text{nV}/\sqrt{\text{Hz}}$
Input Noise Current	$f = 10\text{ kHz}$, $+I_{in}$		3		$\text{pA}/\sqrt{\text{Hz}}$
	$f = 20\text{ kHz}$, $-I_{in}$		20		$\text{pA}/\sqrt{\text{Hz}}$
Differential Gain	$f = 4.43\text{ MHz}$, $R_L = 150\ \Omega$		0.02		%
	$f = 4.43\text{ MHz}$, $R_L = 18.75\ \Omega$		0.02		%
Differential Phase	$f = 4.43\text{ MHz}$, $R_L = 150\ \Omega$		0.02		Degrees
	$f = 4.43\text{ MHz}$, $R_L = 18.75\ \Omega$		0.03		Degrees
DC PERFORMANCE					
Input Offset Voltage	$T_{MIN}-T_{MAX}$		5	12	mV
Offset Drift				15	mV
Input Bias Current (–)	$T_{MIN}-T_{MAX}$		10		$\mu\text{V}/^\circ\text{C}$
			10	135	μA
Input Bias Current (+)	$T_{MIN}-T_{MAX}$			200	μA
			6	12	μA
	$T_{MIN}-T_{MAX}$			20	μA
INPUT CHARACTERISTICS					
Input Resistance	+Input		125		k Ω
	–Input		12.5		Ω
Input Capacitance			2.75		pF
Common-Mode Rejection Ratio	$V_{CM} = \pm 2.5\text{ V}$	50	54		dB
Input Common-Mode Voltage Range			± 2.5		V
Open Loop Transresistance	$V_{OUT} = \pm 2.5\text{ V}$	300	500		k Ω
	$T_{MIN}-T_{MAX}$	250			k Ω
OUTPUT CHARACTERISTICS					
Output Voltage Swing	$R_L = 9\ \Omega$				
$R_L = 18.75\ \Omega$		± 2.1	± 2.5		V
$R_L = 150\ \Omega$		± 2.7	± 3.0		V
Output Current		175	200		mA
Short-Circuit Current			240		mA
Capacitive Load Drive			40		pF
POWER SUPPLY					
Operating Range	T_{MIN} to T_{MAX}	± 4.5		± 6.0	V
Quiescent Current			15.5	17	mA
				20	mA
Power Supply Rejection Ratio		60	66		dB
	$+V_S = +4\text{ V}$ to $+6\text{ V}$, $-V_S = +5\text{ V}$	50	56		dB
	$+V_S = +5\text{ V}$, $-V_S = -4\text{ V}$ to -6 V				dB

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage 12.6 V

Internal Power Dissipation²

Plastic Package (N) Observe Power Derating Curves

Small Outline Package (R) Observe Power Derating Curves

Wide Body SOIC (R-16) Observe Power Derating Curves

Input Voltage (Common-Mode) $\pm V_S$ Differential Input Voltage ± 1.2 V

Output Short Circuit Duration

. Observe Power Derating Curves

Storage Temperature Range N, R -65°C to $+125^{\circ}\text{C}$ Operating Temperature Range (A Grade) -40°C to $+85^{\circ}\text{C}$ Lead Temperature Range (Soldering 10 sec) 300°C **NOTES**

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Specification is for device in free air:

8-Lead Plastic Package: $\theta_{JA} = 90^{\circ}\text{C}/\text{W}$ 8-Lead SOIC Package: $\theta_{JA} = 122^{\circ}\text{C}/\text{W}$ 16-Lead SOIC Package: $\theta_{JA} = 73^{\circ}\text{C}/\text{W}$ **MAXIMUM POWER DISSIPATION**

The maximum power that can be safely dissipated by the AD8010 is limited by the associated rise in junction temperature. The maximum safe junction temperature for plastic encapsulated devices is determined by the glass transition temperature of the plastic, approximately $+150^{\circ}\text{C}$. Temporarily exceeding this limit may cause a shift in parametric performance due to a change in the stresses exerted on the die by the package. Exceeding a junction temperature of $+175^{\circ}\text{C}$ for an extended period can result in device failure.

While the AD8010 is internally short circuit protected, this may not be sufficient to guarantee that the maximum junction temperature ($+150^{\circ}\text{C}$) is not exceeded under all conditions. To ensure proper operation, it is necessary to observe the maximum power derating curves.

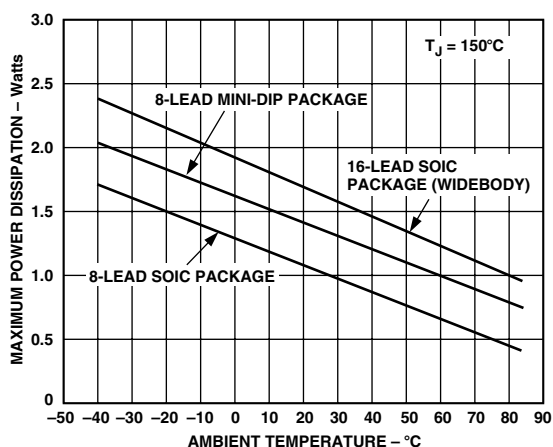


Figure 2. Plot of Maximum Power Dissipation vs. Temperature

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Options
AD8010AN	-40°C to $+85^{\circ}\text{C}$	8-Lead Plastic DIP	N-8
AD8010AR	-40°C to $+85^{\circ}\text{C}$	8-Lead Plastic SOIC	SO-8
AD8010AR-16	-40°C to $+85^{\circ}\text{C}$	16-Lead Wide Body SOIC	R-16
AD8010AR-REEL		REEL SOIC	13" REEL
AD8010AR-REEL7		REEL SOIC	7" REEL
AD8010AR-16-REEL		REEL SOIC	13" REEL
AD8010AR-16-REEL7		REEL SOIC	7" REEL

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8010 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high-energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



AD8010—Typical Performance Characteristics

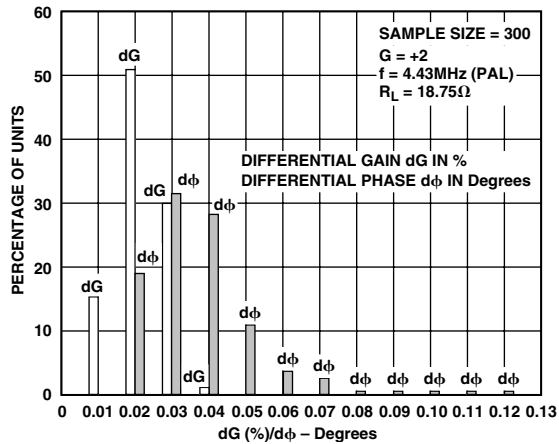


Figure 3. Distribution of Differential Gain (dG) and Differential Phase (dφ); R_L = 18.75 Ω

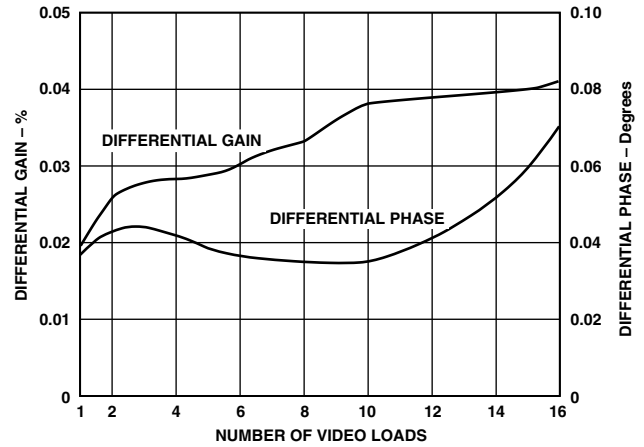


Figure 6. Differential Gain and Phase vs. Number of Video Loads Over Temperature (−40°C to +85°C); f = 4.43 MHz

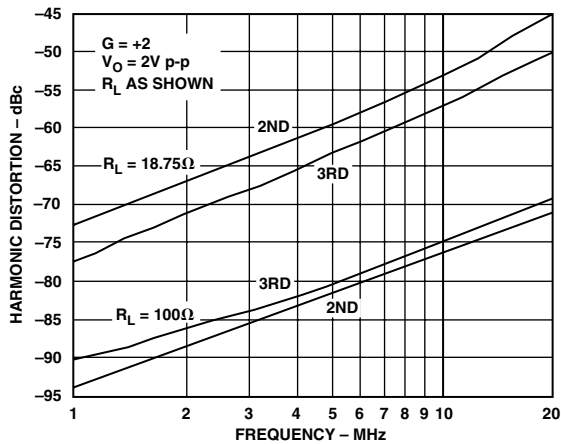


Figure 4. Harmonic Distortion vs. Frequency; G = +2

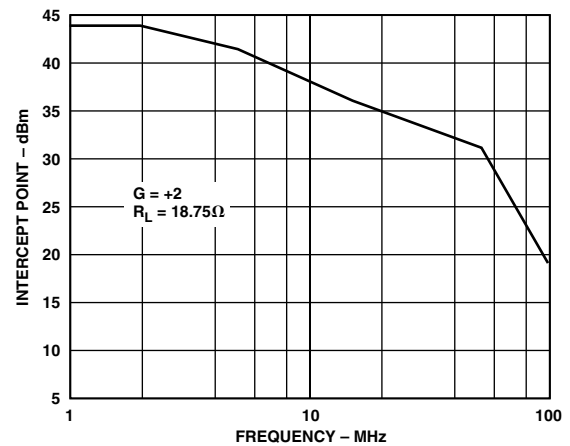


Figure 7. Two-Tone, 3rd Order IMD Intercept vs. Frequency; G = +2, R_L = 18.75 Ω

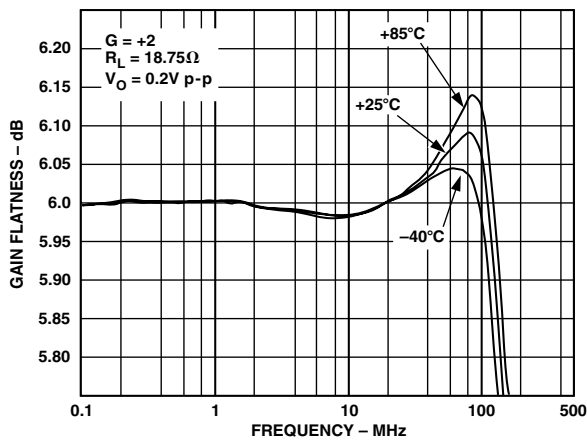


Figure 5. Gain Flatness vs. Frequency Over Temperature (−40°C to +85°C)

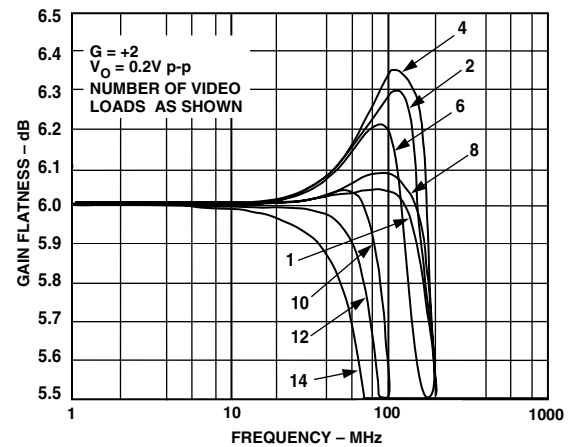


Figure 8. Gain Flatness vs. Frequency vs. Number of Video Loads

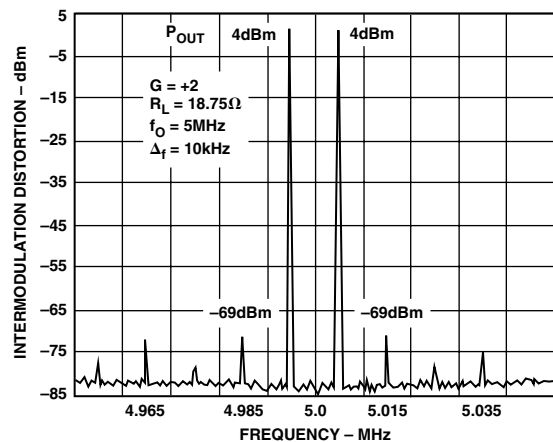


Figure 9. Intermodulation Distortion

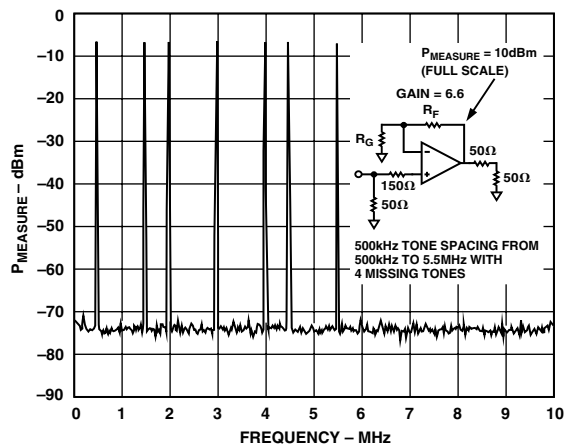


Figure 12. Multitone Distortion; $R_L = 100\ \Omega$

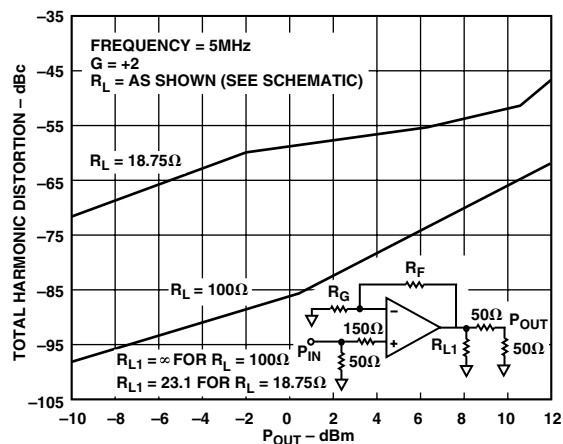


Figure 10. Total Harmonic Distortion vs. P_{OUT} ; $G = +2$

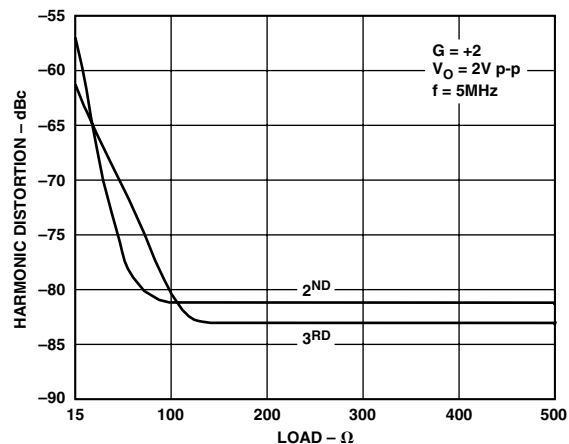


Figure 13. Harmonic Distortion vs. Load

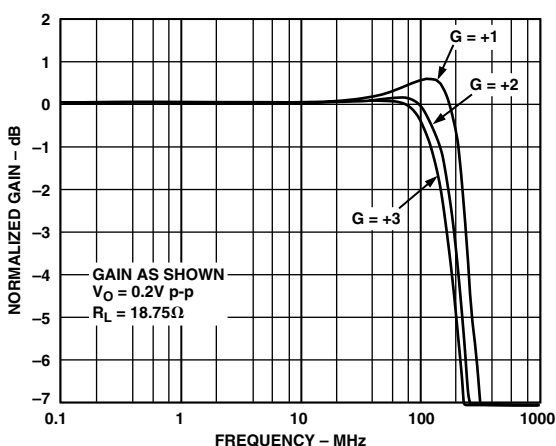


Figure 11. Small Signal Closed-Loop Frequency Response; $R_L = 18.75\ \Omega$

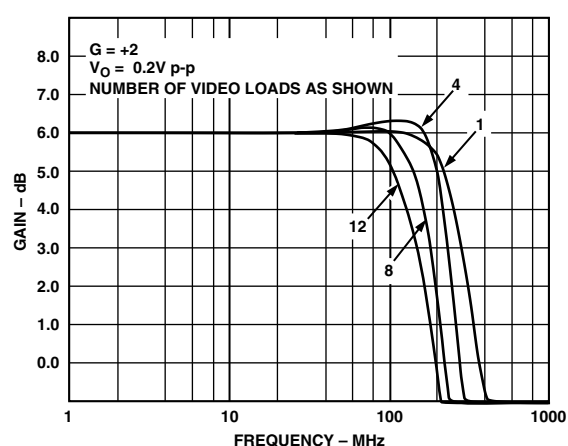


Figure 14. Closed-Loop Frequency Response vs. Number of Video Loads

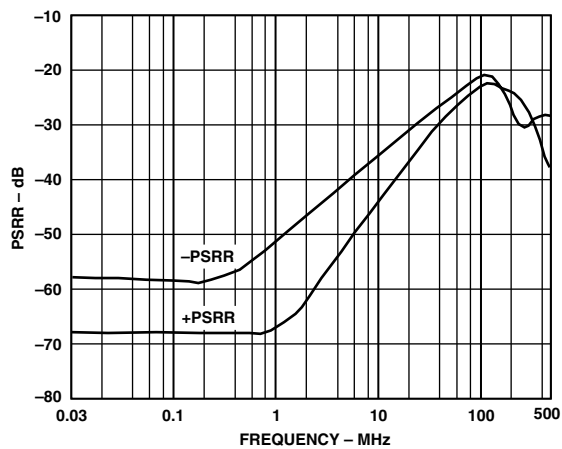


Figure 15. PSRR vs. Frequency

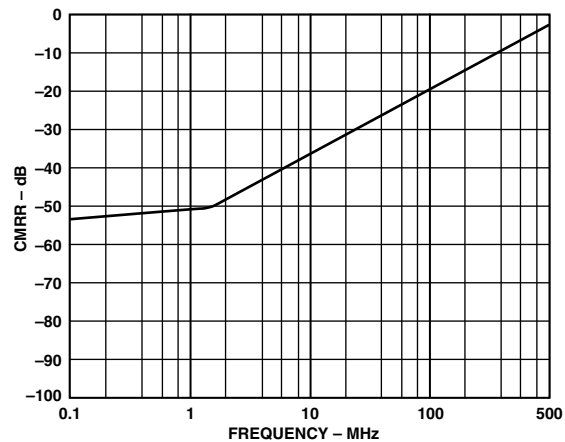


Figure 18. CMRR vs. Frequency

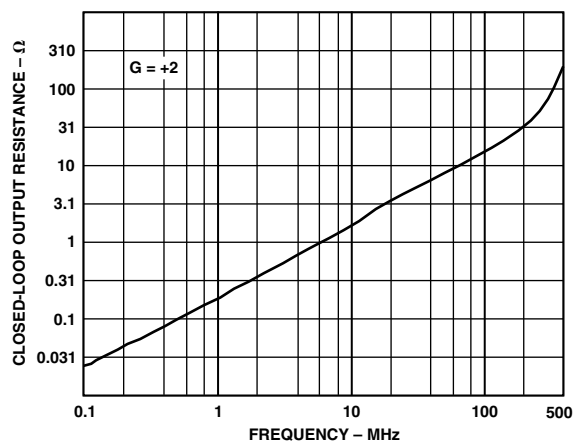


Figure 16. Closed-Loop Output Resistance vs. Frequency

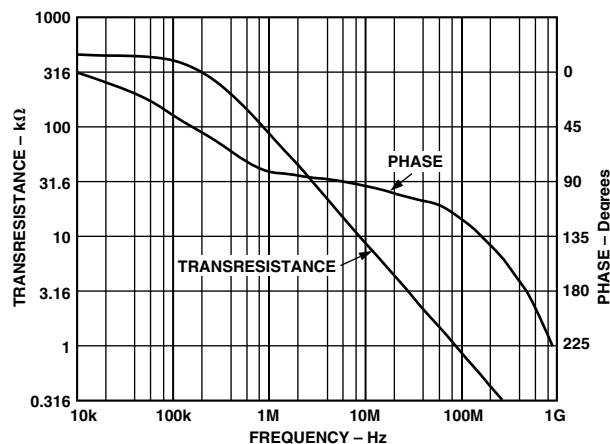


Figure 19. Transresistance and Phase vs. Frequency;
 $R_L = 18.75 \Omega$

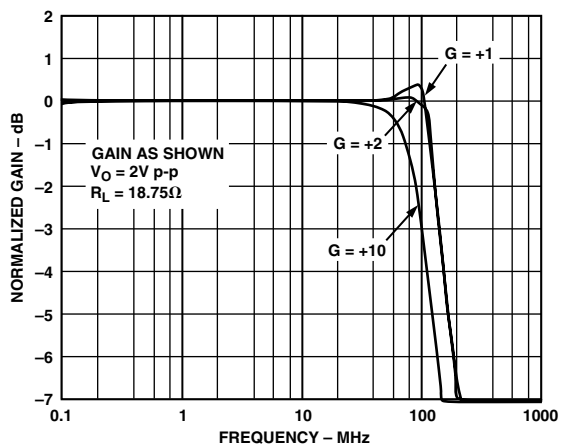


Figure 17. Large Signal Frequency Response; $V_O = 2 \text{ V p-p}$

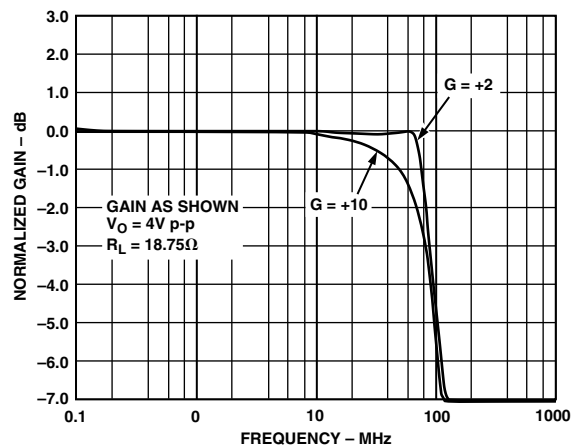


Figure 20. Large Signal Frequency Response; $V_O = 4 \text{ V p-p}$

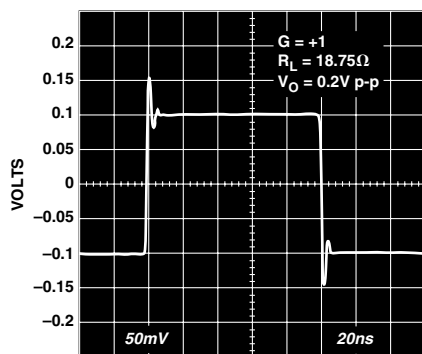
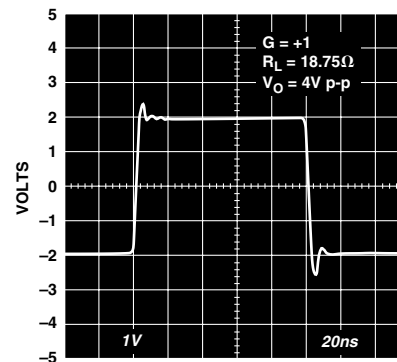
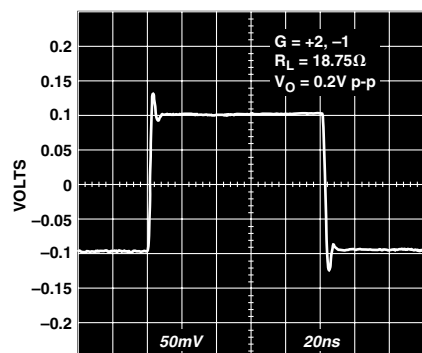
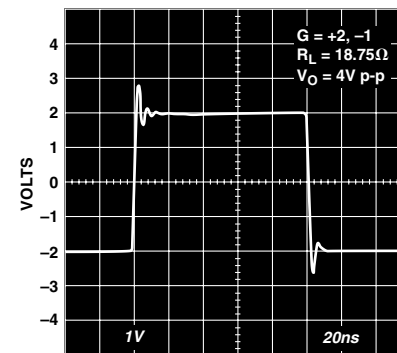
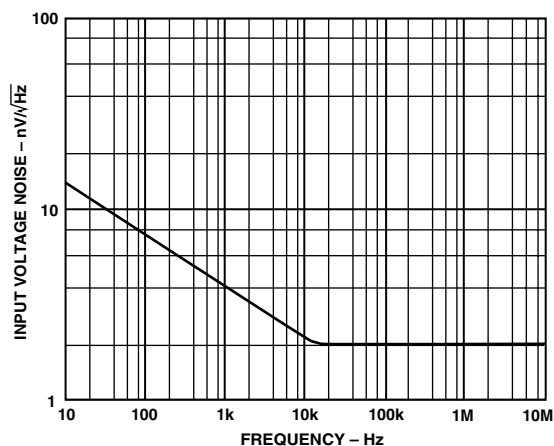
Figure 21. Small-Signal Pulse Response; $G = +1$ Figure 24. Large-Signal Pulse Response; $G = +1$ Figure 22. Small-Signal Pulse Response; $G = +2, -1$ Figure 25. Large-Signal Pulse Response; $G = +2, -1$ 

Figure 23. Input Voltage Noise vs. Frequency

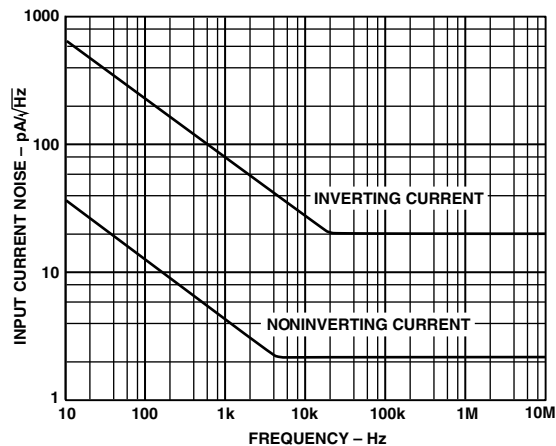


Figure 26. Input Current Noise vs. Frequency

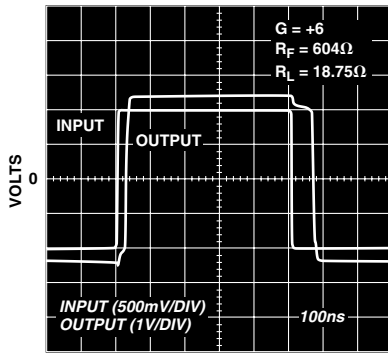


Figure 27. Overdrive Recovery; $G = +6$

OVERDRIVE RECOVERY

Overdrive of an amplifier occurs when the output and/or input range are exceeded. The amplifier must recover from this overdrive condition. As shown in Figure 27, the AD8010 recovers within 35 ns from negative overdrive and within 75 ns from positive overdrive.

THEORY OF OPERATION

The AD8010 is a current feedback amplifier optimized for high current output while maintaining excellent performance with respect to flatness, distortion and differential gain/phase. As a video distribution amplifier, the AD8010 will drive up to 12 parallel video loads (12.5Ω) from a single output with 0.04% differential gain and 0.04° differential phase errors. This means that, unlike designs with one driver per output, any output is a true reflection of the signal on all other outputs.

The high output current capability of the AD8010 also make it useful in xDSL applications. The AD8010 can drive a 12.5Ω single-ended or 25Ω differential load with low harmonic distortion. This makes it useful in designs that utilize a step-up transformer to drive a twisted-pair transmission line.

To achieve these levels of performance special precautions with respect to supply bypassing are recommended (Figure 29). This configuration minimizes the contribution from high frequency supply rejection to differential gain and phase errors as well as reducing distortion due to harmonic energy in the power supplies.

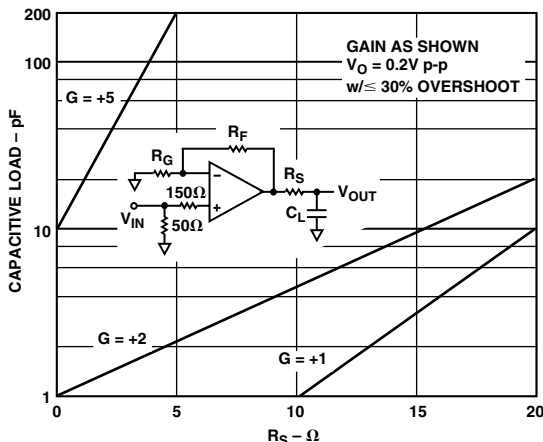


Figure 28. Capacitive Load Drive vs. Series Resistor for Various Gains

Driving Capacitive Loads

The AD8010 was designed primarily to drive nonreactive loads. If driving loads with a capacitive component is desired, best frequency response is obtained by the addition of a small series resistance as shown in Figure 28. The inset figure shows the optimum value for R_{SERIES} vs. capacitive load. It is worth noting that the frequency response of the circuit when driving large capacitive loads will be dominated by the passive roll-off of R_{SERIES} and C_L .

LAYOUT CONSIDERATIONS

The specified high speed performance of the AD8010 requires careful attention to board layout and component selection. Proper R_F design techniques and low-pass parasitic component selection are necessary.

The PCB should have a ground plane covering all unused portions of the component side of the board to provide low impedance path. The ground plane should be removed from the area near the input pins to reduce the parasitic capacitance.

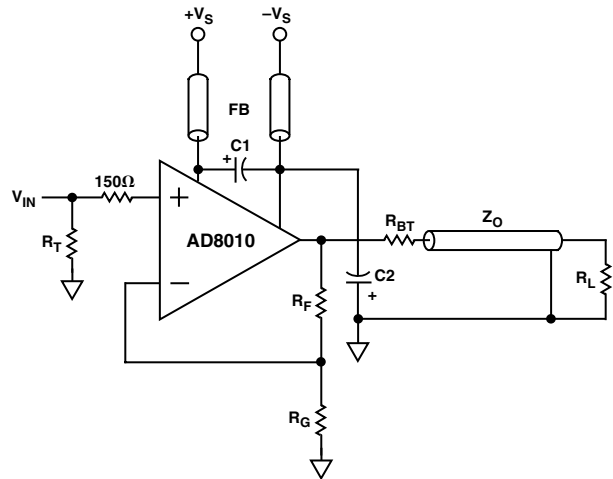


Figure 29. Standard Noninverting Closed-Loop Configuration with Recommended Bypassing Technique

The standard noninverting closed-loop configuration with the recommended power supply bypassing technique is shown in Figure 29. Ferrite beads (Amidon Associates, Torrance CA, Part Number 43101) are used to suppress high frequency power supply energy on the DUT supply lines at the DUT. C1 and C2 each represent the parallel combination of a $47 \mu\text{F}$ (16 V) tantalum electrolytic capacitor, a $10 \mu\text{F}$ (10 V) tantalum electrolytic capacitor and a $0.1 \mu\text{F}$ ceramic chip capacitor. Connect C1 from the $+V_S$ pin to the $-V_S$ pin. Connect C2 from the $-V_S$ pin to signal ground.

The feedback resistor should be located close to the inverting input pin in order to keep the parasitic capacitance at this node to a minimum. Parasitic capacitances of less than 1 pF at the inverting input can significantly affect high speed performance.

Stripline design techniques should be used for long traces (greater than about 3 cm). These should be designed with a characteristic impedance (Z_O) of 50Ω or 75Ω and be properly terminated at each end.

AD8010

Differential Line Driver

Twisted pair transmission lines are more often being used for high frequency analog and digital signals. Over long distances, however, the attenuation characteristics of these lines can degrade the performance of the transmission system. To compensate for this, larger signals are transmitted, which after the attenuation, will still have useful signal strength.

The high output current of two AD8010s can be used along with a transformer to create a high power differential line driver. The differential configuration effectively doubles the output swing, while the step-up transformer further increases the output voltage.

In the circuit in Figure 31 the A device is configured as a gain-of-two follower, while the B device is a gain-of-two inverter. These will produce a differential output signal whose maximum value is twice the peak-to-peak value of the maximum output of one device. For this circuit a 12 V peak-to-peak output can be obtained.

The op amps drive a 1:2 step-up transformer that drives a 100 Ω transmission line. Since the impedance reflected back to the primary varies as the square of the turns ratio, it will appear as 25 Ω at the primary. This source terminating resistor is split as a 12.4 Ω resistor at the output of each device.

The circuit shown is capable of delivering 12 V p-p to the line and operates with a -3 dB bandwidth of 40 MHz. The peak current output of either op amp is 100 mA.

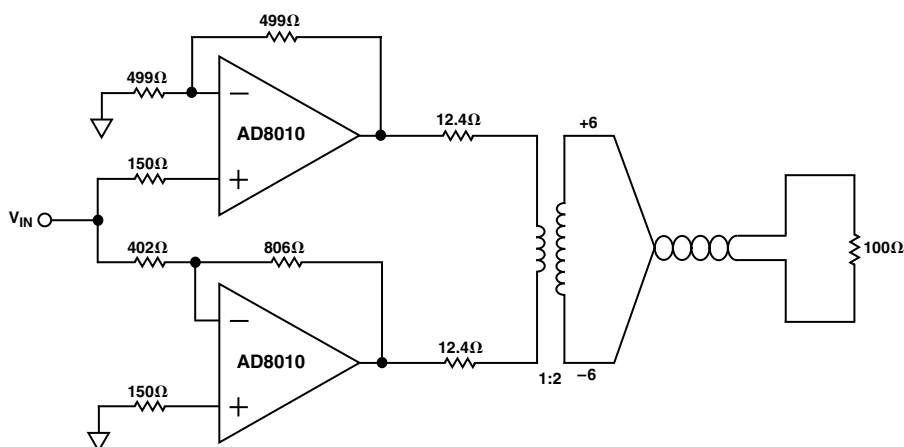


Figure 31. High Output Differential Line Driver Using Two AD8010s.
NOTE: Please see Figure 29 for Recommended Bypassing Technique.

Closed-Loop Gain and Bandwidth

The AD8010 is a current feedback amplifier optimized for use in high performance video and data acquisition applications. Since it uses a current feedback architecture, its closed-loop -3 dB bandwidth is dependent on the magnitude of the feedback resistor. The desired closed-loop bandwidth and gain are obtained by varying the feedback resistor (R_F) to set the bandwidth, and varying the gain resistor (R_G) to set the desired gain. The characteristic curves and specifications for this data sheet reflect the performance of the AD8010 using the values of R_F noted at the top of the specifications table. If a greater -3 dB bandwidth and/or slew rate is required (at the expense of video performance), Table I provides the recommended resistor values. Figure 32 shows the test circuit and conditions used to produce Table I.

Effect of Feedback Resistor Tolerance on Gain Flatness

Because of the relationship between the 3 dB bandwidth and the feedback resistor, the fine scale gain flatness will, to some extent, vary with feedback resistor tolerance. It is therefore recommended that resistors with a 1% tolerance be used if it is desired to maintain flatness over a wide range of production lots. In addition, resistors of different construction have different associated parasitic capacitance and inductance. Metal-film resistors were used for the bulk of the characterization for this data sheet. It is possible that values other than those indicated will be optimal for other resistor types.

Quality of Coaxial Cable

Optimum flatness when driving a coax cable is possible only when the driven cable is terminated at each end with a resistor matching its characteristic impedance. If the coax was ideal, then the resulting flatness would not be affected by the length of the cable. While outstanding results can be achieved using inexpensive cables, it should be noted that some variation in flatness due to varying cable lengths may be experienced.

Table I. -3 dB Bandwidth and Slew Rate vs. Closed-Loop Gain and Resistor Values

Package: N-8

Closed-Loop Gain	R_F (Ω)	R_G (Ω)	-3 dB BW (MHz)	Slew Rate (V/ μ s)
+1	453	∞	285	900
+2	374	374	255	900
+5	348	86.6	200	800
+10	562	61.9	120	550

Package: R-16

Closed-Loop Gain	R_F (Ω)	R_G (Ω)	-3 dB BW (MHz)	Slew Rate (V/ μ s)
+1	412	∞	245	900
+2	392	392	220	900
+5	392	97.6	160	800
+10	604	66.5	95	550

Package: SO-8

Closed-Loop Gain	R_F (Ω)	R_G (Ω)	-3 dB BW (MHz)	Slew Rate (V/ μ s)
+1	392	∞	345	950
+2	374	374	305	1000
+5	348	86.6	220	1000
+10	499	54.9	135	650

1. $V_O = 0.2$ V p-p for -3 dB Bandwidth.
2. $V_O = 2$ V p-p for Slew Rate.
3. Bypassing per Figure 29.

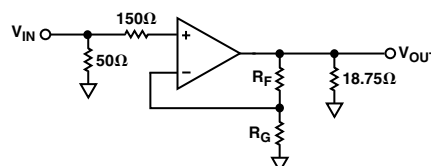
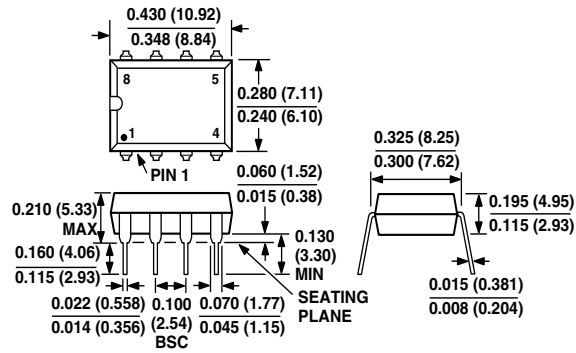
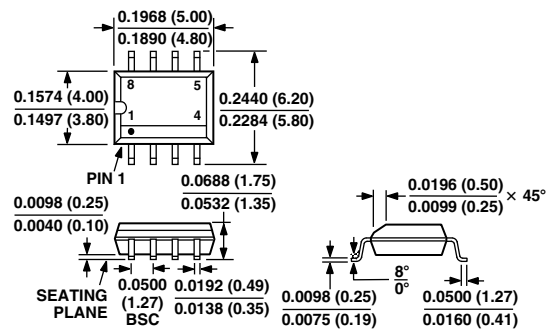


Figure 32. Test Circuit for Table I

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

8-Lead Plastic Mini-DIP
(N-8)8-Lead SOIC
(SO-8)16-Lead Wide Body SOIC
(R-16)